NSN 5961-01-328-1761

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view Online at https://aerobasegroup.com/hsh/5961-01-326-1761
Inclosure Material:
Metal
Overall Length:
1.453 inches
Function For Which Designed:
Voltage regulator
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-5
Mounting Method:
Threaded stud
Features Provided:
Quality assurance level tx and burn in and hermetically sealed case and reverse polarity
Overall Width Across Flats:
Between 0.667 inches and 0.687 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
9.1 regulator voltage
Voltage Tolerance In Percent:
-5.0/+5.0
Current Rating Per Characteristic:
5.24 amperes source cutoff current horsepower metric
Power Rating Per Characteristic:
50.0 watts any acceptable preset
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 tab, solder lug
Specification Data:
81349-mil-s-19500/358 government specification
Shalf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0